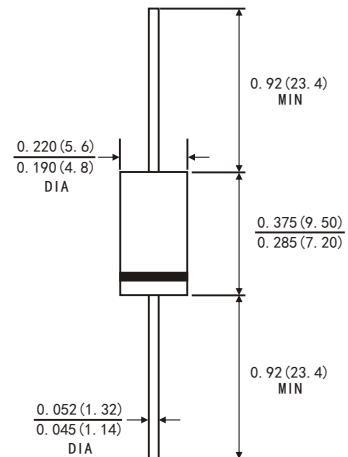


## FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU and WEEE 2012/19/EU



## DO-201AD



Dimensions in inches and (millimetres)

## MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams

## TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

## PRIMARY CHARACTERISTICS

I <sub>F(AV)</sub>	5.0A
V <sub>RRM</sub>	80V
I <sub>FSM</sub>	120A
V <sub>F</sub> at I <sub>F</sub> =5.0A,125°C	0.50V
T <sub>JMAX</sub>	150°C

## MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified )

Parameter	Symbol	SB580L	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	80	V
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I <sub>F(AV)</sub>	5.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL)	I <sub>FSM</sub>	120	A
Operating junction temperature range	T <sub>J</sub>	-55 to+150	°C
Storage temperature range	T <sub>stg</sub>	-55 to+150	°C

## RATINGS AND CHARACTERISTIC OF SB580L

### ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Test Conditions		Symbol	TYP.	MAX.	Unit
Instantaneous forward voltage	$I_F=5.0\text{A}$	$T_A=25^\circ\text{C}$	$V_F$ <sup>1)</sup>	0.54	0.58	V
		$T_A=100^\circ\text{C}$		0.52	—	
		$T_A=125^\circ\text{C}$		0.50	—	
		$T_A=25^\circ\text{C}$		0.45	—	
		$T_A=100^\circ\text{C}$		0.38	—	
	$I_F=2.0\text{A}$	$T_A=125^\circ\text{C}$		0.35	—	
		$T_A=25^\circ\text{C}$		20	50	$\mu\text{ A}$
		$T_A=100^\circ\text{C}$		1.7	—	mA
		$T_A=125^\circ\text{C}$		6.5	—	
Typical junction capacitance	4V, 1MHz		$C_J$	340		pF

Notes: 1.Pulse test: 300  $\mu\text{s}$  pulse width, 1% duty cycle

2.Pulse test: pulse width  $\leq 40\text{ms}$

### THERMAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Symbol	SB580L	Unit
Typical thermal resistance <sup>3)</sup>	$R_{\theta JA}$	25.0	$^\circ\text{C}/\text{W}$
	$R_{\theta JL}$	8.0	

3.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

# RATINGS AND CHARACTERISTIC OF SB580L

FIG.1-FORWARD CURRENT DERATING CURVE

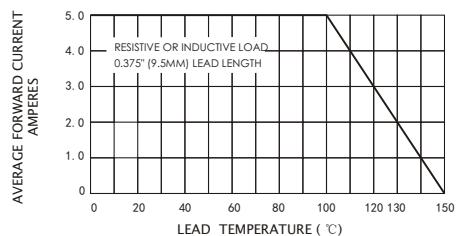


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

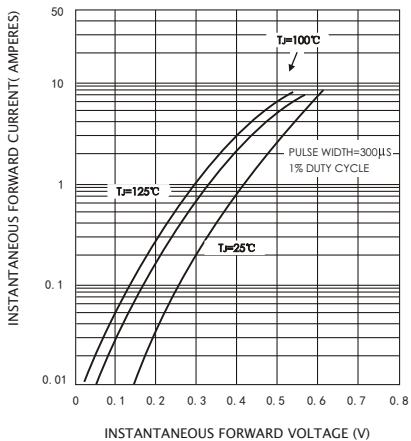


FIG.5-TYPICAL JUNCTION CAPACITANCE

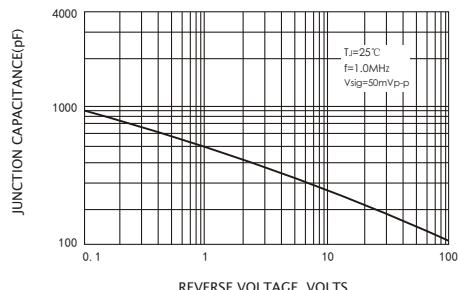


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

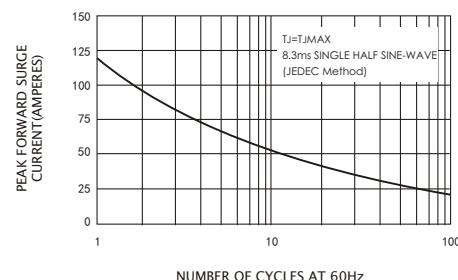


FIG.4-TYPICAL REVERSE CHARACTERISTICS

